

**PT481/PT481F/
PT483F1**

■ Features

1. Epoxy resin package
2. Narrow acceptance ($\Delta \theta$: Typ. $\pm 13^\circ$)
3. High sensitivity

(I_C : MIN. 1.5mA at $E_e = 0.1\text{mW/cm}^2$) :

PT481/PT483F1

(I_C : MIN. 0.9mA at $E_e = 0.1\text{mW/cm}^2$) :

PT481F

4. Visible light cut-off type : **PT481F/PT483F1**
5. Long lead pin type : **PT483F1**

■ Applications

1. VCRs, cassette tape recorders
2. Floppy disk drives
3. Optoelectronic switches
4. Automatic stroboscopes

■ Absolute Maximum Ratings (Ta = 25°C)

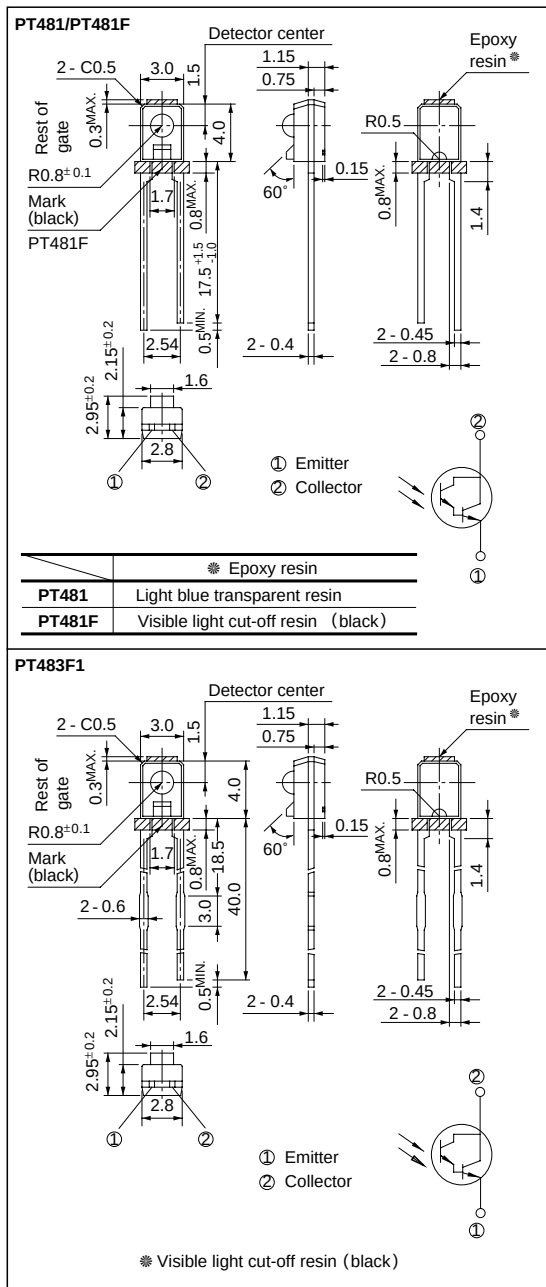
Parameter	Symbol	Rating	Unit
Collector-emitter voltage	V_{CEO}	35	V
Emitter-collector voltage	V_{ECO}	6	V
Collector current	I_C	50	mA
Collector power dissipation	P_C	75	mW
Operating temperature	T_{opr}	- 25 to +85	°C
Storage temperature	T_{stg}	- 40 to +85	°C
*1Soldering temperature	T_{sol}	260	°C

*1 For 3 seconds at the position of 1.4mm from the bottom face of resin package

Narrow Acceptance High Sensitivity Phototransistor

■ Outline Dimensions

(Unit : mm)



Electro-optical Characteristics

(Ta = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*2 Collector current	PT481	Ic	VCE = 2V Ee = 0.1mW/cm ²	1.5	10	25	mA
	PT481F			0.9	-	27	mA
	PT483F1			1.5	-	4.0	mA
Collector dark current		ICEO	VCE = 10V, Ee = 0	-	-	10 ⁻⁶	A
*2 Collector-emitter saturation voltage		VCE(sat)	Ic = 2.5mA Ee = 1mW/cm ²	-	0.7	1.0	V
Peak emission wavelength	PT481	λp	-	-	800	-	nm
	PT481F/PT483F1			-	860	-	nm
Response time	Rise time	tr	VCE = 2V, Ic = 10mA	-	80	-	μs
	Fall time	tf	RL = 100Ω	-	70	-	μs

*2 Ee : Irradiance by CIE standard light source A (tungsten lamp)

Fig. 1 Collector Power Dissipation vs. Ambient Temperature

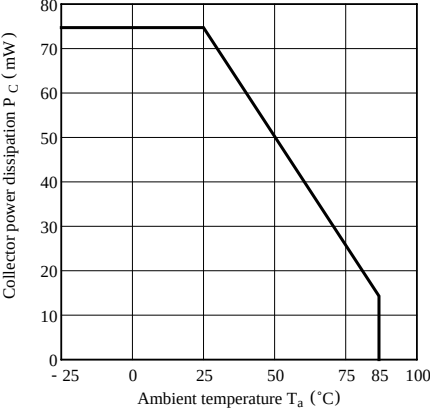


Fig. 2 Collector Dark Current vs. Ambient Temperature

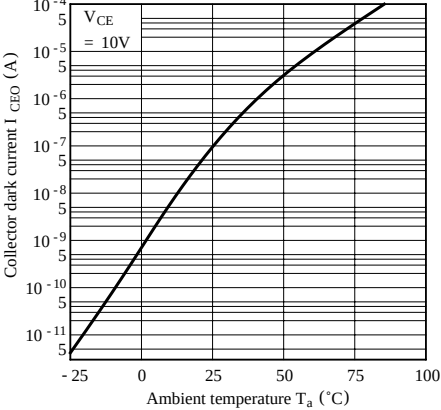


Fig. 3 Relative Collector Current vs. Ambient Temperature

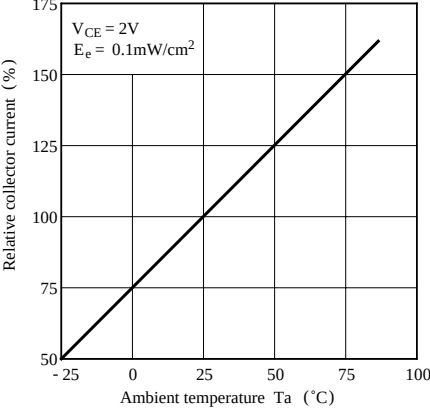


Fig.4-a Collector Current vs. Irradiance (PT481)

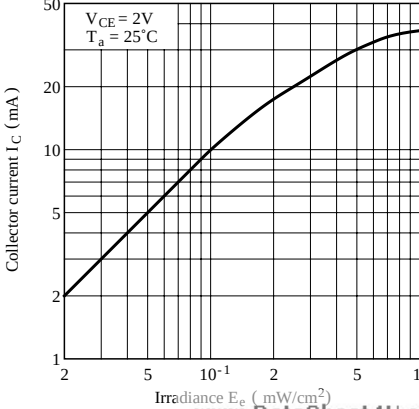


Fig.4-b Collector Current vs. Irradiance
(PT481F/PT483F1)

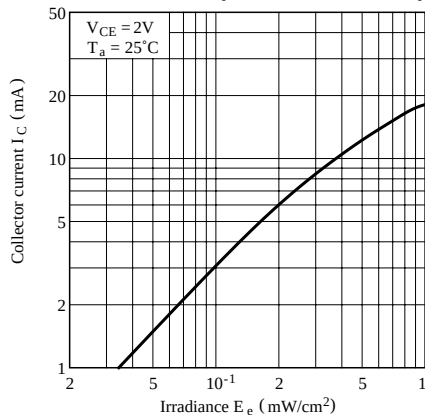


Fig.5-a Collector Current vs. Collector-emitter Voltage
(PT481)

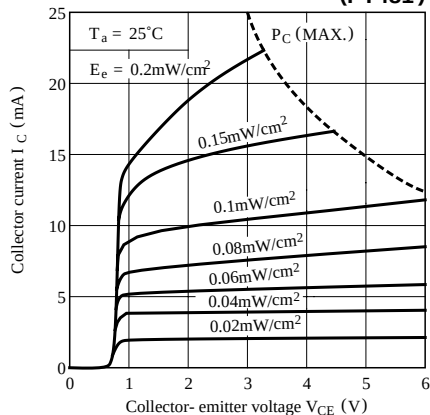


Fig.5-b Collector Current vs. Collector-emitter Voltage
(PT481F/PT483F1)

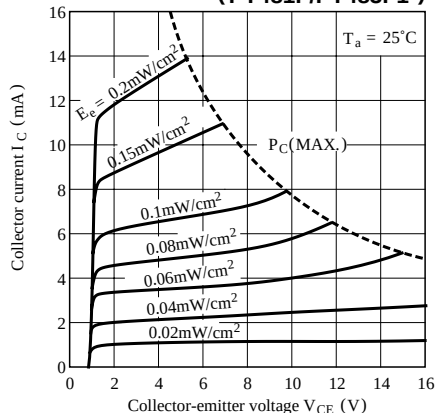


Fig. 6 Spectral Sensitivity

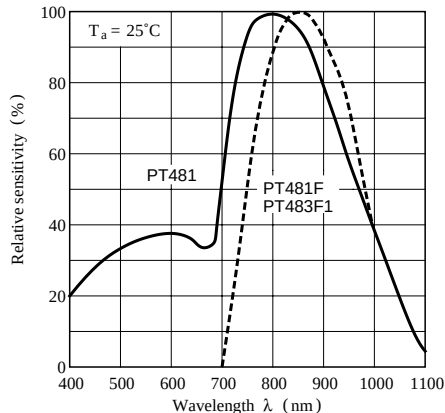
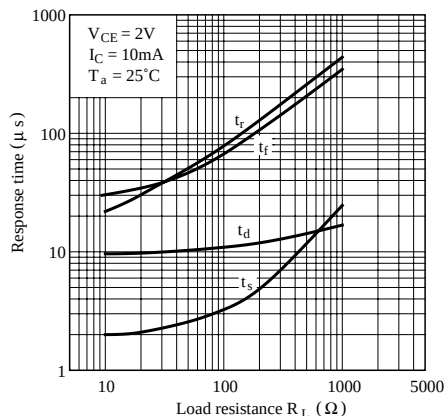


Fig. 7 Response Time vs. Load Resistance



Test Circuit for Response Time

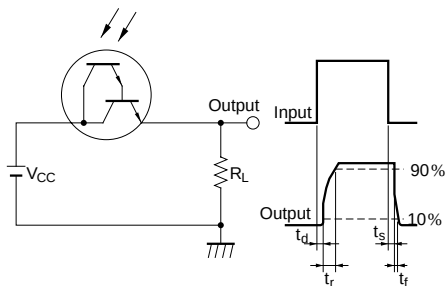


Fig. 8 Sensitivity Diagram

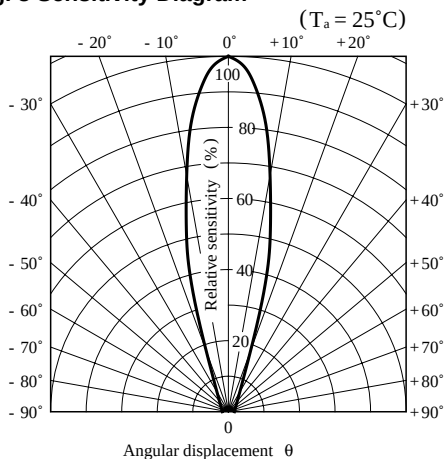


Fig.9-a Collector-emitter Saturation Voltage vs. Irradiance (PT481)

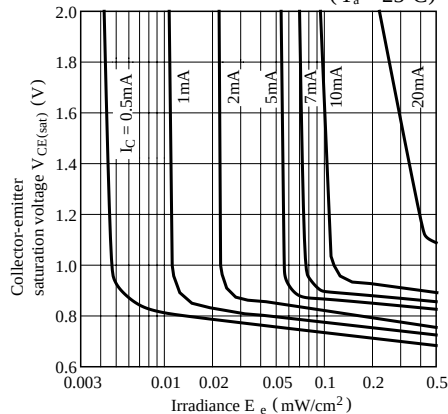


Fig.9-b Collector-emitter Saturation Voltage vs. Irradiance (PT481F/PT483F1)

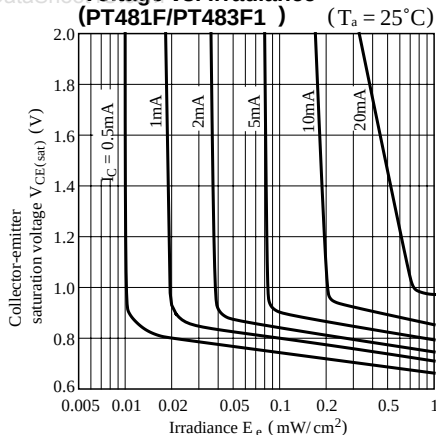
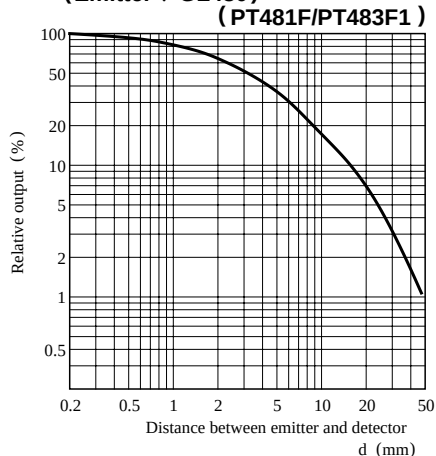


Fig.10 Relative Output vs. Distance (Emitter : GL480)



- Please refer to the chapter “Precautions for Use.”